

X-Band GaN Solid State Power Amplifier

VSX3614 High-Power X-Band SSPA

X-band Solid State Power Amplifiers are Efficient, High Power, and Compact with proven GaN transistor technology

Features

- High efficiency GaN transistors
- BIT and controls via EIA-422 remote connection
- 900 W pulsed modules
- 1.5 kW to 6 kW power combined

CPI-Built RF Bricks

CPI's VSX3614 Solid State Power Amplifiers are rock-solid, highly-efficient and easy to maintain. The VSX3614 Solid State Power Amplifier is designed for use in radar applications and cover the 8.8 – 9.6 GHz frequency band. Gallium Nitride transistors are combined into 900 W bricks which are air cooled. The 900 W bricks can be power-combined using waveguide combiners for higher power transmitters.

X Band SSPA Output Power 1400 1200

Optimized for Pulsed Radars

This amplifier utilizes GaN transistors to provide high gain, high efficiency and excellent pulse fidelity. The result is excellent AM/PM, phase-noise and spectral regrowth performance. This amplifier is compliant to NTIA regulatory requirements for this frequency with the appropriately shaped input pulse.

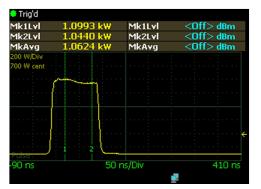


The information listed above represents typical data for the product . The data should be used for basic information only. Formal, controlled specifications should be obtained from CPI for use in equipment design.

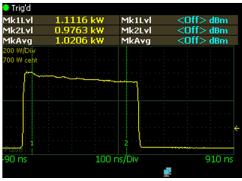




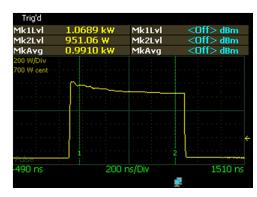
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100 nsec PW, 1 kHz PRF



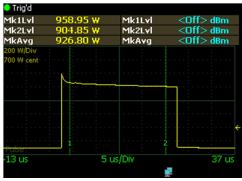
500 nsec PW, 1 kHz PRF



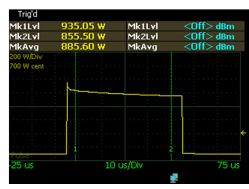
1 μsec PW, 1 kHz PRF



10 μsec PW, 1 kHz PRF



25 μsec PW, 1 kHz PRF 42 VDC @ 3.1 A



50 μsec PW, 1 kHz PRF 42 VDC @ 5.2 A



100 μsec PW, 1 kHz PRF 10% Duty 42 VDC @ 9.4 A

Note: All Power Plots Measured at 9.41 GHz

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X-Band GaN Solid State Power Amplifier

| Specifications | |
|-----------------------------|--|
| Frequency Range | 8.8 to 9.6 GHz |
| Peak RF Output | 900 W saturated |
| Pulse Width | 1 to 100 usec (typical) |
| Pulse Droop | 0.6 dB maximum |
| Duty Cycle | 10% maximum |
| Output Power Flatness | 1 dB across Frequency Range |
| Small Signal Gain | 28 dB nominal |
| Input VSWR | 1.5:1 maximum |
| Output VSWR | 1.5:1 maximum |
| Harmonic Output | -35dBc maximum |
| Interpulse Thermal Noise | -110 dBc / MHz maximum |
| Noise Power Density | -100 dBc into a 100 MHz bandwidth |
| NTIA Compliance | With appropriately shaped input pulse. |

| Specifications | |
|-------------------------------|---|
| Prime Power | 42 VDC @ 9.5 Amps |
| Ambient Temperature | -30C to +50C operating |
| Relative Humidity | 100% non-condensing |
| Altitude | 30,000 feet operating, 70,000 feet non- operating |
| Shock and Vibration | Ruggedized for Harsh Environments. |
| Cooling | Forced air |
| RF Input Connection | SMA female |
| RF Output Connection | ½ height WR90 |
| RF Output and VSWR Monitor | Control Connector |
| Dimensions (width) | 6 " Plus Connectors |
| Dimensions (height) | 2" |
| Dimensions (depth) | 11.5" |
| Weight | 10 lbs max. |

The values listed above represent specified limits for the product and are subject to change. The data should be used for basic information only. Formal, controlled specifications may be obtained from CPI for use in equipment design.



Certificate Number: 11607